

(Lab)

- N.B.** (1) Question No. 1 is compulsory.
 (2) Solve any four questions from remaining.
 (3) Assume suitable additional data whenever necessary.

3pm to 6pm

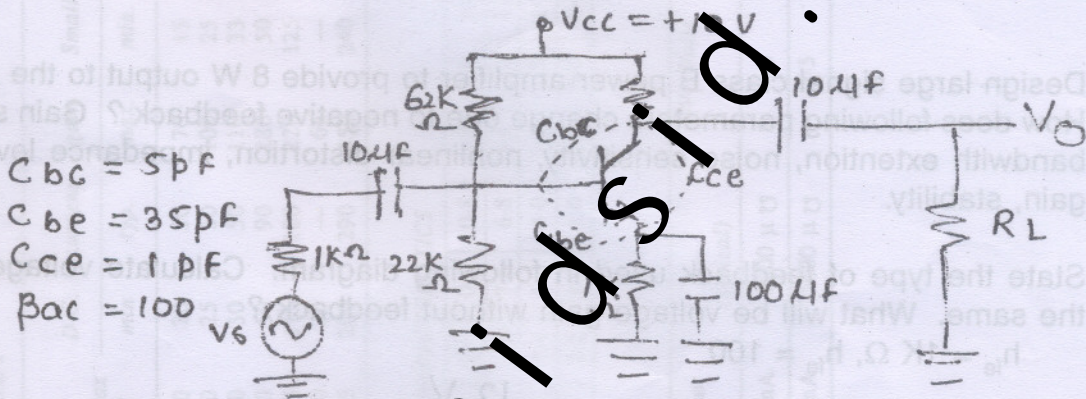
1. Design the two stage R-C coupled CS amplifier to meet the following specifications. 20

$|A_v| \geq 1000, S_{ICO} \leq 10, F_L \leq 20 \text{ Hz}, V_{CC} = 12 \text{ V}$

Find V_o rms, R_{in} , R_o .

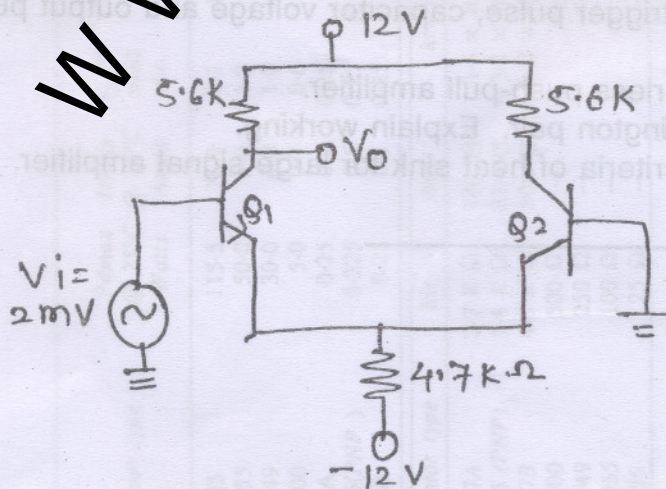
Given : $h_{ie} = 2.7 \text{ K}\Omega, h_{oe} = 18 \mu\Omega, h_{fe} = 200, h_{re} = 1.5 \times 10^{-4}$. Draw the diagram with designed values.

2. (a)



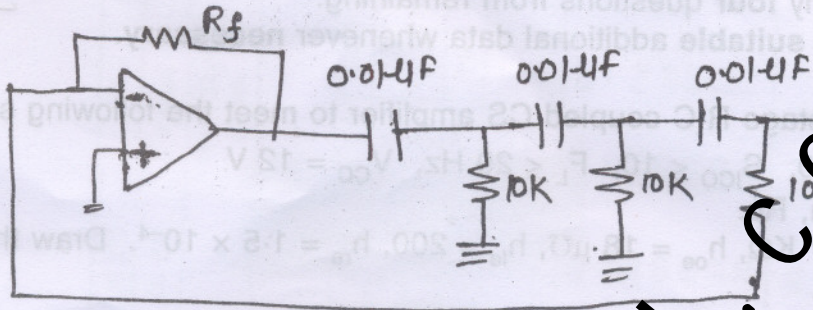
- (i) Determine total low frequency response i.e. low frequency due to input RC circuit, bypass RC circuit, output RC circuit. 5
 (ii) Determine total high frequency response. 5
 (iii) Determine bandwidth of circuit. 2
 (b) (i) Determine bandwidth of two stage amplifier in which each stage has lower critical frequency of 300 Hz and upper critical frequency of 1000 KHz. 4
 (ii) Why coupling capacitor of an amplifier do not have significant effect on gain at high signal frequencies? 4

3. (a) Prove that for Wien-bridge oscillator, gain of feedback loop is 1/3. 10
 (b) Derive the formula for resonant frequency for Wien-bridge oscillator. 5
 (c) Find single ended output voltage V_o for the following circuit. 5



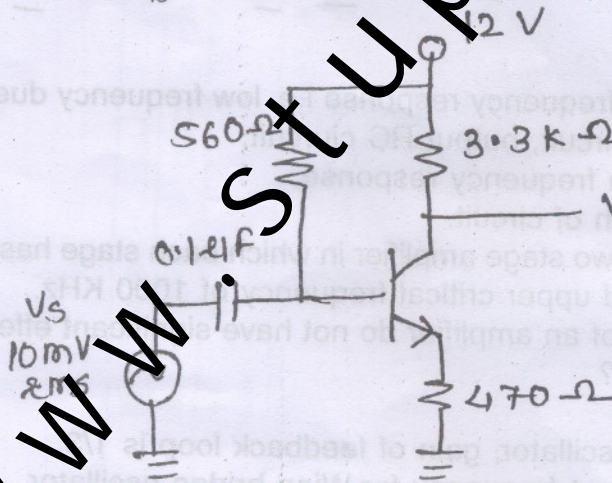
$\beta_1 = \beta_2 = 100$
 $R_i = 11 \text{ K}\Omega$

4. (a) Explain with block diagram different topologies of negative feedback amplifier. What is improvement in A_v , A_i ? 10
- (b) Determine value of R_f necessary for the following circuit to operate as an oscillator. Determine frequency of oscillation. 10



5. (a) Design large signal class B power amplifier to provide 8 W output to the 4Ω load. How does following parameters change due to negative feedback? Gain selectivity, bandwidth extension, noise sensitivity, nonlinear distortion, impedance level, circuit gain, stability. 10
- (b) State the type of feedback used in following diagram. Calculate voltage gain for the same. What will be voltage gain without feedback? 10

$h_{ie} = 1K \Omega$, $h_{fe} = 100$



- (b) Explain working of monostable multivibrator created by modifying Schmitt trigger. Draw the waveforms of input trigger pulse, capacitor voltage and output pulse. 10
7. (a) Explain working of transformerless push-pull amplifier. 10
- (b) (i) Draw the diagram of Darlington pair. Explain working. 5
- (ii) Briefly explain selection criteria of heat sink for large signal amplifier. 5

DATA SHEET

Transistor type	P_{dmax}	I_{cmax}	$V_{CE}^{(sat)}$	V_{CBO}	V_{CEO}	V_{CER}	V_{CEX}	V_{BE0}	T_j max	D.C. current gain			S_{min}	S_{typ}	h_{fe}	V_{BE} max.	θ_{jc}	Derate above 25°C
	@ 25°C Watts	@ 25°C Amps	volt d.c.	volt d.c.	(Sus) volt d.c.	(Sus) volt d.c.	volt d.c.	volt d.c.		min	typ.	max.						
2N 3055	115.5	15.0	1.1	100	60	70	90	7	200	20	50	70	15	50	120	1.8	1.5	0.7
ECN 055	50.0	5.0	1.0	60	50	55	60	5	200	25	50	100	25	75	125	1.5	3.5	0.4
ECN 149	30.0	4.0	1.0	50	40	—	—	8	150	30	50	110	33	60	115	1.2	4.0	0.3
ECN 100	5.0	0.7	0.6	70	60	65	—	6	200	50	90	280	50	90	280	0.9	35	0.05
BC147A	0.25	0.1	0.25	50	45	50	—	6	25	115	180	220	125	220	260	0.9	—	—
2N 525(PNP)	0.225	0.5	0.25	85	30	—	—	—	100	35	—	65	—	45	—	—	—	—
BC147B	0.25	0.1	0.25	50	45	50	—	6	125	200	290	450	240	330	500	0.9	—	—

Transistor type	h_{ie}	h_{oe}	h_{re}	θ_{ja}
BC 147A	2.7 K Ω	18 μ Ω	1.5×10^{-4}	0.4°C/mw
2N 525 (PNP)	1.4 K Ω	25 μ Ω	3.2×10^{-4}	—
BC 147B	4.5 K Ω	30 μ Ω	2×10^{-4}	0.4°C/mw
ECN 100	500 Ω	—	—	—
ECN 149	250 Ω	—	—	—
ECN 055	100 Ω	—	—	—
2N 3055	25 Ω	—	—	—

BFW 11 - JFET MUTUAL CHARACTERISTICS

$-V_{GS}$ Volts	0.0	0.2	0.4	0.6	0.8	1.0	1.2	1.6	2.0	2.4	2.5	3.0	3.5	4.0
I_{DS} max. mA	10	9.0	8.3	7.6	6.8	6.1	5.4	4.2	3.1	2.2	2.0	1.1	0.5	0.0
I_{DS} typ. mA	7.0	6.0	5.4	4.6	4.0	3.3	2.7	1.7	0.8	0.2	0.0	0.0	0.0	0.0
I_{DS} min. mA	4.0	3.0	2.2	1.6	1.0	0.5	0.0	0.0	0.0	0.0	0.0	0.0	0.0	0.0

N-Channel JFET

Type	V_{DS} max. Volts	V_{DG} max. Volts	V_{GS} max. Volts	P_d max. @25°C	T_j max.	I_{DSS}	g_{mo} (typical)	$-V_p$ Volts	r_d	Derate above 25°C	θ_{ja}
2N3822	50	50	50	300 mW	175°C	2 mA	3000 μ Ω	6	50 K Ω	2 mW/°C	0.59°C/mW
BFW 11 (typical)	30	30	30	300 mW	200°C	7 mA	5600 μ Ω	2.5	50 K Ω	—	0.59° C/mW

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